

DMTH10H032LPDWQ 100V 175°C DUAL CHANNEL ENHANCEMENT MODE MOSFET

PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C	
100V	32mΩ @ V _{GS} = 10V	24A	
	50mΩ @ V _{GS} = 4.5V	19A	

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- **DC-DC** converters
- Motors

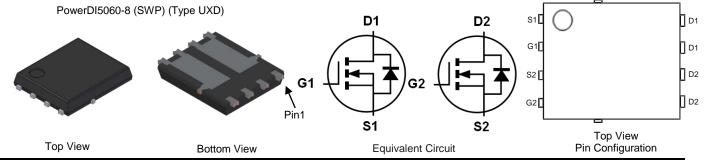
Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Low Input Capacitance Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Additional Tin-Plated on Sidewall Pads for Optical Solder
- Inspection Lead-Free Finish: RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH10H032LPDWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 gualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8 •
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

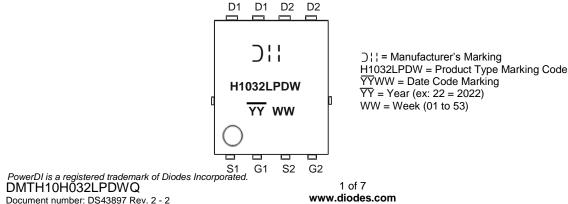
	Part Number	Baakaga	Packing				
Part Number		Package	Qty.	Carrier			
	DMTH10H032LPDWQ-13	PowerDI5060-8 (SWP) (Type UXD)	2500	Tape & Reel			
Notes:	1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.						

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	V
Gate-Source Voltage	Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	١D	24 17	А
Maximum Body Diode Forward Current	ls	24	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	96	А
Pulsed Body Diode Forward Current (10µs Pulse, T _C = +25°C, Package L	lsм	96	А
Avalanche Current, L = 0.3mH	las	13	А
Avalanche Energy, L = 0.3mH	EAS	25.3	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Thermal Resistance, Junction to Ambient (Note 5)		Reja	50	°C/W
Total Power Dissipation	T _A = +25°C	PD	3	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	3.8	°C/W
Total Power Dissipation	T _C = +25°C	PD	37	W
Operating and Storage Temperature Range	•	TJ, TSTG	-55 to +175	°C

Electrical Characteristics Q1 N-Channel (@Tc = +25°C, unless otherwise specified.)

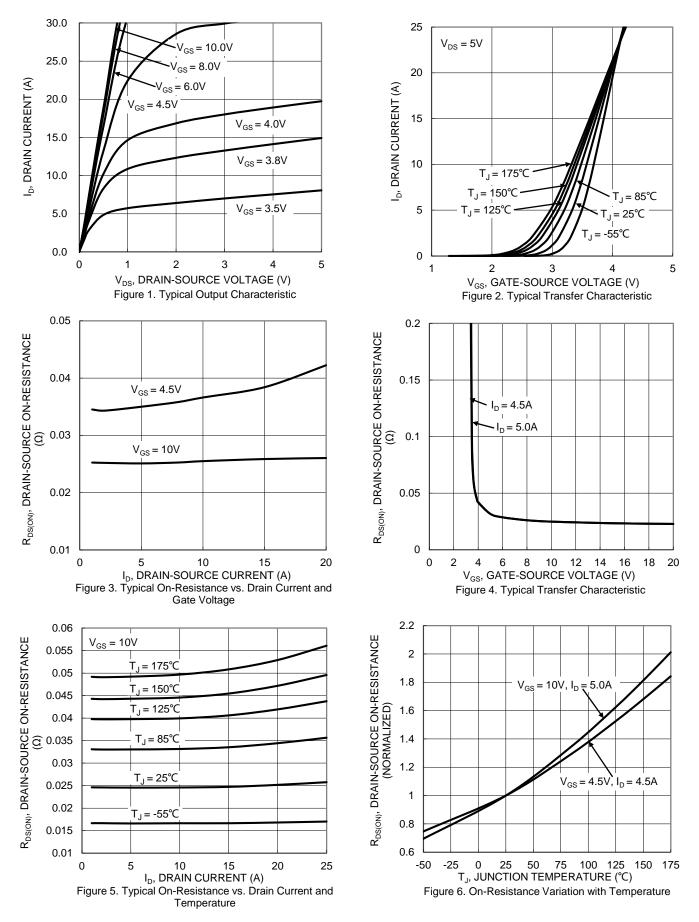
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			, ,,	I			
Drain-Source Breakdown Voltage	BV _{DSS}	100	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	V _{DS} = 80V, V _{GS} = 0V	
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	1.3	—	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	24	32	$V_{GS} = 10V, I_D = 5A$	$V_{GS} = 10V, I_D = 5A$	
Static Drain-Source On-Resistance	Rds(on)	_	34	50	mΩ	V _{GS} = 4.5V, I _D = 4.5A	
Diode Forward Voltage	Vsd	_	0.8	1	V	$V_{GS} = 0V, I_S = 5A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	683	_	pF		
Output Capacitance	Coss		165	—	pF	VDS = 50V, VGS = 0V, − f = 1MHz	
Reverse Transfer Capacitance	Crss	_	6.9	—	pF		
Gate Resistance	Rg	_	1.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	6.3	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	11.9	—	nC		
Gate-Source Charge	Qgs	_	2.0	—	nC	$V_{DS} = 50V, I_D = 6A$	
Gate-Drain Charge	Q _{gd}	_	3.1	—	nC		
Turn-On Delay Time	t _{D(ON)}	_	4.1	—	ns		
Turn-On Rise Time	tR	_	4.5	—	ns	$V_{DS} = 50V, R_{L} = 5.85\Omega$	
Turn-Off Delay Time	tD(OFF)	—	12.5	—	ns	$V_{GS} = 10V, R_g = 3\Omega$	
Turn-Off Fall Time	tF	_	9.3	—	ns		
Reverse Recovery Time	t _{RR}	_	31.5	_	ns		
Reverse Recovery Charge	Q _{RR}		94.6	_	nC	IF = 6A, di/dt = 500A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

before information of the substrate recordad, 202 copper, with information square
Thermal resistance from junction to solder point (on the exposed drain pin).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



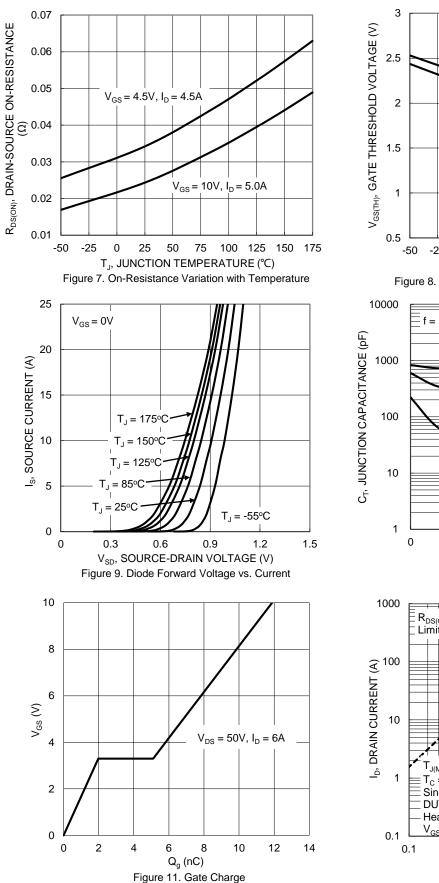
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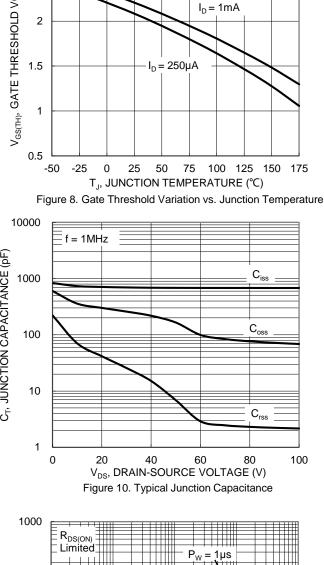


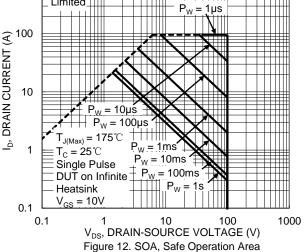
DMTH10H032LPDWQ Document number: DS43897 Rev. 2 - 2



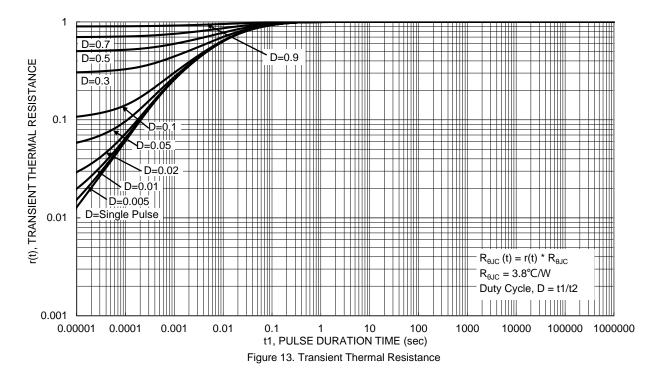
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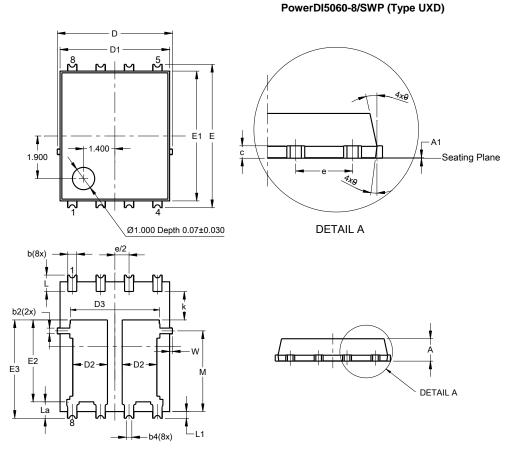






Package Outline Dimensions

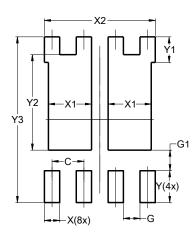
Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8/SWP (Type UXD) Dim Min Max Typ 0.90 1.10 1.00 А A1 0.00 0.05 -b 0.30 0.50 0.41 b2 0.20 0.35 0.25 b4 0.25REF С 0.230 0.330 0.277 D 5.15 BSC 5.10 D1 4.70 4.90 D2 1.46 1.66 1.55 D3 3.78 4.18 3.98 6.40 BSC Ε E1 5.60 6.00 5.80 E2 3.66 3.46 3.86 E2a 4.195 4.595 4.395 1.27BSC е k 1.05 -----0.635 0.835 L 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 3.605 Μ 3.205 4.005 W 0.025 0.225 0.125 θ 12° 10° 11° θ1 6° 8° 7° All Dimensions in mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8/SWP (Type UXD)

Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	1.720		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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